

USB Charger Emulator with Adjustable Power Switch and Load Detection

FEATURES

- 45 mΩ High-Side MOSFET
- 0.5~4.0 A (typ.) Adjustable Current Limit
- Ultra-Low Load Detection
- Support Apple® Devices fast charging (Apple® 2.1A / 2.4A mode)
- Support Samsung Galaxy Tab Devices fast Charging
- Support BC1.2 & YD/T 1591-2009 Charging Spec
- Built-in Soft-Start
- Support single layer PCB layout.
- 4.5 ~ 6.5V Single Supply Operation.
- Available EMSOP8 package.

APPLICATIONS

- USB Charger
- USB Wall Adapter
- Car Charger

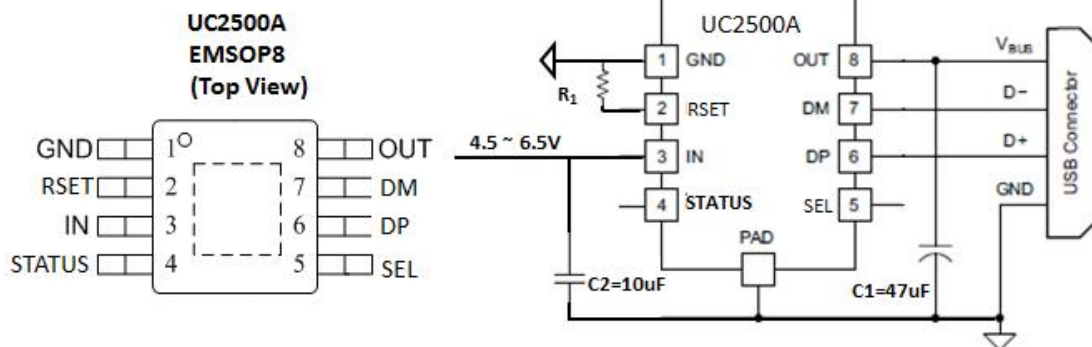
DESCRIPTION

The UC2500A integrated USB charger emulators with automatic host charger identification circuitry and high performance adjustable current limiting power switch. An automatic USB charger identification circuit allows mobile power supply can automatically provides the correct modes on the data lines to charger compliant devices among the Apple, Samsung and BC1.2 modes.

The UC2500A is a 45mΩ power switch intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. This also provides hiccup mode when enter OTSD.

The UC2500A provides a STATUS pin for ultra-low load detection or USB cable resistance compensation and an SEL pin to select 10W or 12W mode in application.

PACKAGE AND APPLICATION



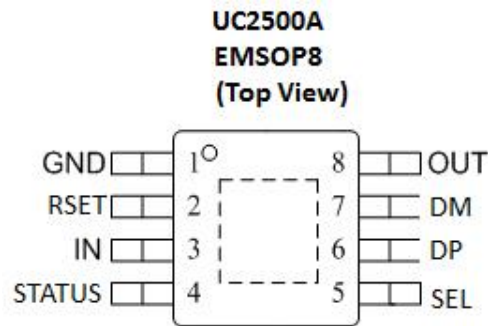
SEL = 0: Apple=2.4A, SS=2A, DCP=1.5A;
 SEL = 1 or Floating: Apple=2.1A, SS=2A, DCP=1.5A;
 STATUS is floating or pull up with 10k Resistor if not used

ORDING INFORMATION

Part Number	Package Type	Package Qty	Op Temp(°C)	Mark
UC2500A	EMSOP8	3000	-40~85	UC2500A XXX

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PINOUT

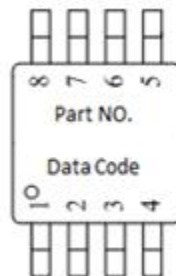


PIN FUNCTIONS

NO.	NAME	TYPE ⁽¹⁾	DESCRIPTION
1	GND	G	Ground connection
2	RSET	I	External resistor used to set current-limit threshold;
3	IN	P/I	Power supply/Input voltage connected to Power Switch; connect a 1 μ F or greater ceramic capacitor from IN to GND as close to the IC as possible
4	STATUS	O	Active-low open-drain output, asserted when the load exceeds the load-detection threshold
5	SEL	I	Logic-level control input; When it is high or floating, DP/DM operate in 2.1A mode , when it is Low, DP/DM operate in 2.4A mode;
6	DP	O/I	DP data line to connector, output for hand-shake voltage to portable equipment, high impedance while disabled
7	DM	O/I	DM data line to connector, input for hand-shake voltage from portable equipment high impedance while disabled
8	OUT	O	Power-switch output, connected to VBUS of USB; connect a 22 μ F or greater ceramic capacitor from OUT to GND as close to the IC as possible

(1) G = Ground, I = Input, O = Output, P = Power

MARK INFORMATION



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ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	MAX	UNIT
Supply Voltage Range	IN	-0.3	7.0	V
Input voltage range	DP,DM	-0.3	5.8	
Continuous output sink current	DP input current, DM input current		35	mA
Continuous output source current	DP output current, DM output current		35	
ESD rating, Human Body Model (HBM)	IN		4	kV
	DP, DM		4	
Operating Junction Temperature	T _J	-40	125	°C
Storage Temperature Range	T _{stg}	-65	150	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

THERMAL METRIC (EMSOP8)			UNIT
θ_{JA}	Junction-to-ambient thermal resistance	65	°C/W
θ_{JCtop}	Junction-to-case (top) thermal resistance	53	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	13.5	
θ_{JB}	Junction-to-board thermal resistance	37	

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

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RECOMMENDED OPERATING CONDITIONS

PARAMETER		MIN	MAX	UNIT
V_{IN}	Input voltage of IN	4.5	6.5	V
$V_{DP/DM}$	DP data line input voltage		5.5	
$I_{DP/DM}$	Continuous sink/source current		±10	mA
R_{SET}	Resistance of R_{SET}	13	100	kΩ
I_{OUT}	Continuous sink/source current	500	4000	mA
T_J	Operating Junction Temperature	-40	125	°C

ELECTRICAL CHARACTERISTICS

Conditions are: $T_A = 25^{\circ}\text{C}$, $V_{IN} = 5.0\text{ V}$, $V_{SEL} = V_{IN}$ and $R_{SET} = 33.0\text{ k}\Omega$. Positive current are into pins. All voltages are with respect to GND (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Switch						
R _{DS(on)}	EMSOP8 Package	I _{OUT} =1A		45	68	mΩ
Current Limit						
I _{OUT}		R _{set} =33.0k	2.50	2.84	3.15	A
Hiccup Mode						
T _{ON_HICCUP}	ON Time of Hiccup mode			130		ms
T _{OFF_HICCUP}	OFF Time of Hiccup mode			1.3		s
Load Detection						
I _{LD_RISING}	I _{OUT} Rising Load Detection Thresold	R _{set} =33.0k	135	195	255	mA
I _{LD_FALLING}	I _{OUT} Falling Load Detection Thresold		90	145	200	
T _{LD_SET}	Load Detection Set time			128		ms
T _{LD_RESET}	Load Detection Reset time			128		
Thermal Shutdown						
	Temperature Rising Threshold			172		°C
	Hysteresis			20		

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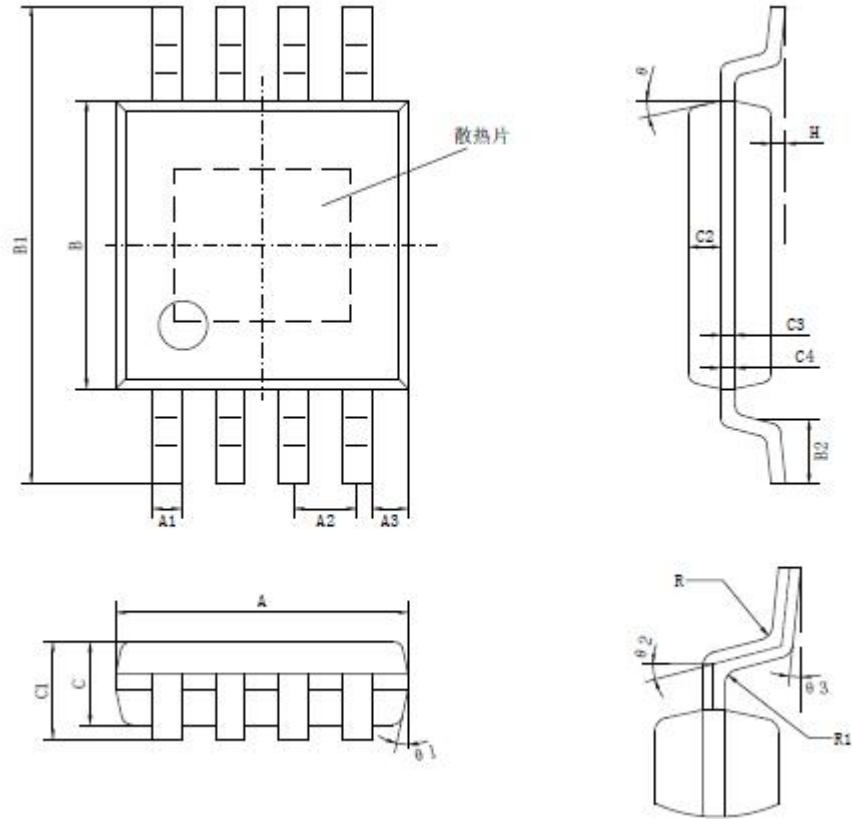
ELECTRICAL CHARACTERISTICS

Conditions are: $T_A = 25^{\circ}\text{C}$, $V_{IN} = 5.0\text{ V}$, $V_{SEL} = V_{IN}$ and $R_{SET} = 33.0\text{ k}\Omega$. Positive current are into pins. All voltages are with respect to GND (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
UNDERVOLTAGE LOCKOUT						
V_{UVLO}	IN rising UVLO threshold voltage		3.75	3.95	4.15	V
	Hysteresis			100		mV
SUPPLY CURRENT						
I_{IN}	IN supply current			160	350	μA
BC 1.2 DCP MODE (SHORT)						
R_{DPM_SHORT}	DP / DM shorting resistance			125	200	Ω
IPAD MODE 2.1A Mode (SEL=1 or Floating)						
V_{DP_IPAD}	DP output voltage		2.5	2.7	2.9	V
V_{DM_IPAD}	DM output voltage		1.85	2.0	2.15	V
IPAD MODE 2.4A Mode (SEL=0)						
V_{DP_IPAD}	DP output voltage		2.5	2.7	2.9	V
V_{DM_IPAD}	DM output voltage		2.5	2.7	2.9	V
Galaxy Tab MODE						
V_{DP_GAL}	DP output voltage		1.1	1.2	1.3	V
V_{DM_GAL}	DM output voltage		1.1	1.2	1.3	

PACKAGE INFORMATION

EMSOP8



标注	尺寸	最小(mm)	最大(mm)	标注	尺寸	最小(mm)	最大(mm)
A		2.90	3.10	C3		0.152	
A1		0.28	0.35	C4		0.15	0.23
A2		0.65TYP		H		0.02	0.15
A3		0.375TYP		θ		12° IYP4	
B		2.90	3.10	θ1		12° IYP4	
B1		4.70	5.10	θ2		14° IYP	
B2		0.45	0.75	θ3		0° ~ 6°	
C		0.75	0.95	R		0.15TYP	
C1		--	1.10	R1		0.15TYP	
C2		0.328TYP					

* 注：EMSOP8产品框架基岛尺寸为1.80X1.80，散热片尺寸为1.80X1.55（单位：mm）